

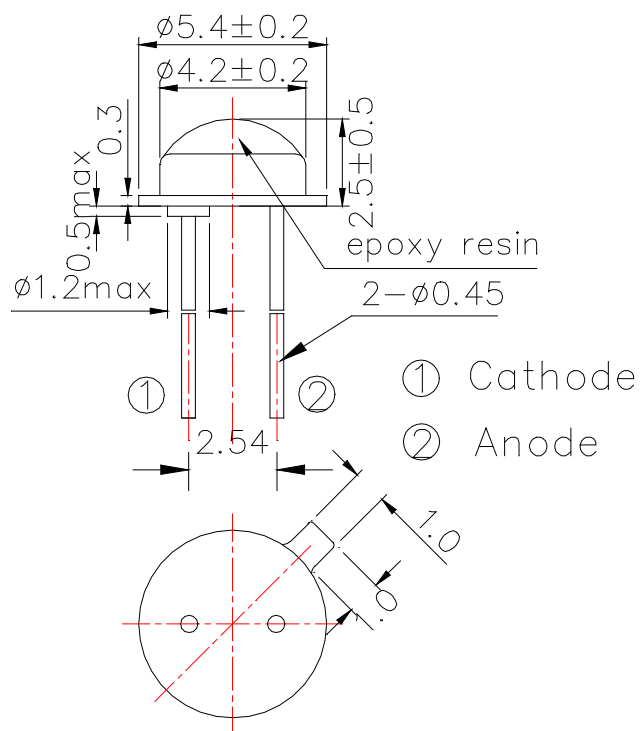
Data Sheet

L505-30K00

Stem type LED Lamp

USHIO

Outline and Internal Circuit



(Unit : mm)

Features

- Chip Material : InGaN
- Chip Dimension : 350um * 300um
- Number of Chips : 1pce
- Peak Wavelength : 505nm typ.
- Stem: TO-46 type
- Lens : Epoxy Resin

Application

Absolute Maximum Ratings (Tc=25°C)

Item	Symbol	Ratings	Unit
Power Dissipation	PD	200	mW
Forward Current	IF	50	mA
Pulse Forward Current	IFP	100	mA
Reverse Voltage	VR	5	V
Thermal Resistance	Rthja	250	K/W
Junction Temperature	Tj	120	°C
Operating Temperature	Topr	-40 ~ +100	°C
Storage Temperature	Tstg	-40 ~ +100	°C
Soldering Temperature	TSOL	250	°C

‡Pulse Forward Current condition : Duty 1% and Pulse Width=10us.

‡Soldering condition: Soldering condition must be completed within 5 seconds at 250°C and is allowed in the area apart 3mm from the bottom of the lamp.

Optical and Electrical Characteristics (Tc=25°C)

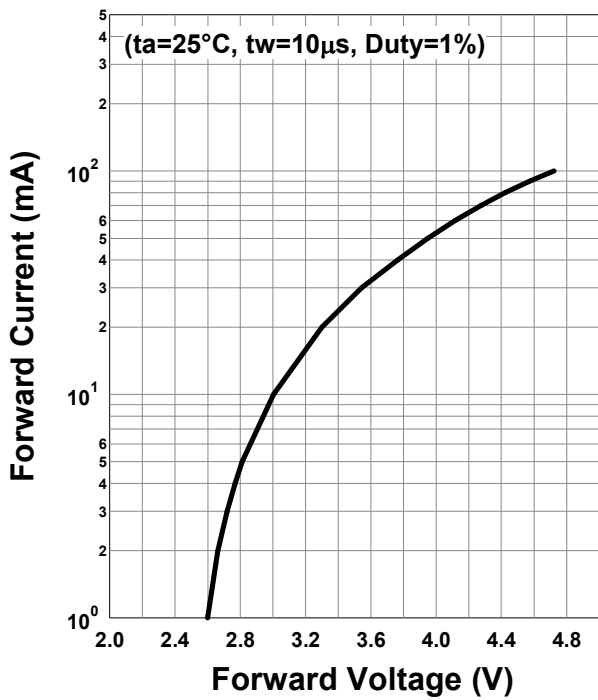
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage	VF		3.3	4.0	V	IF=20mA
	VFP		4.7			IFP=100mA
Total Radiated Power	PO		8		mW	IF=20mA
			22			IFP=100mA
Radiant Intensity	IE		6		mW/sr	IF=20mA
			16			IFP=100mA
Brightness	lv		930		mcd	IF=20mA
Luminous Flux	Φ_V		3200		mlm	IF=20mA
Peak Wavelength	λ_p	495		515	nm	IF=20mA
Dominant Wavelength	λ_D		508		nm	IF=20mA
Half Width	$\Delta\lambda$		30		nm	IF=20mA
Viewing Half Angle	$\theta_{1/2}$		±62		deg.	IF=20mA
Rise Time	tr		25		ns	IF=20mA
Fall Time	tf		70		ns	IF=20mA

‡ Radiated Power is measured by S3584-08.

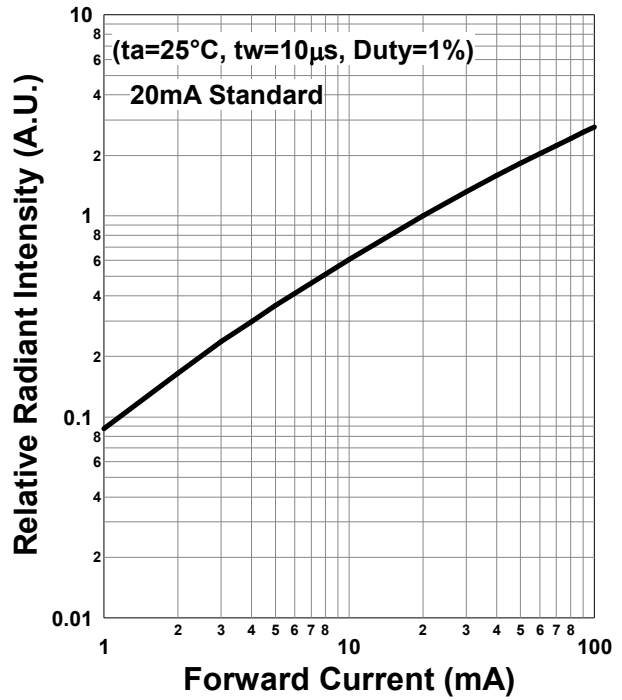
‡ Radiant Intensity is measured by CIE127-2007 Condition B.

Typical Characteristic Curves

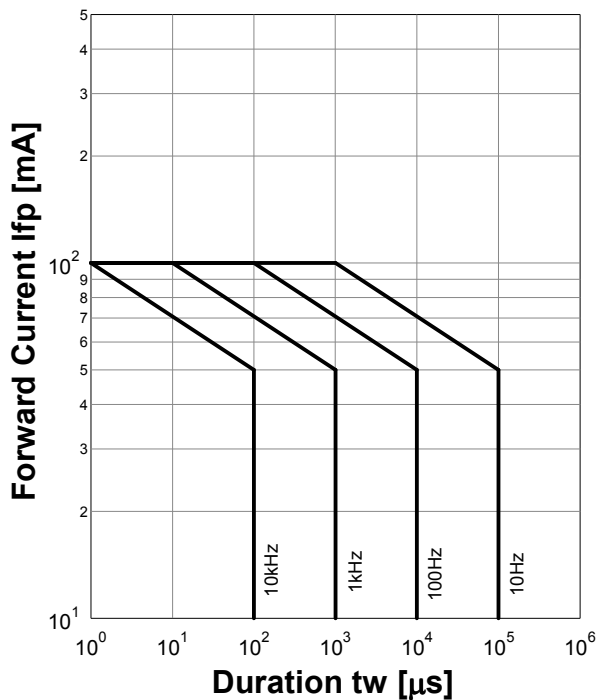
Forward Current - Forward Voltage



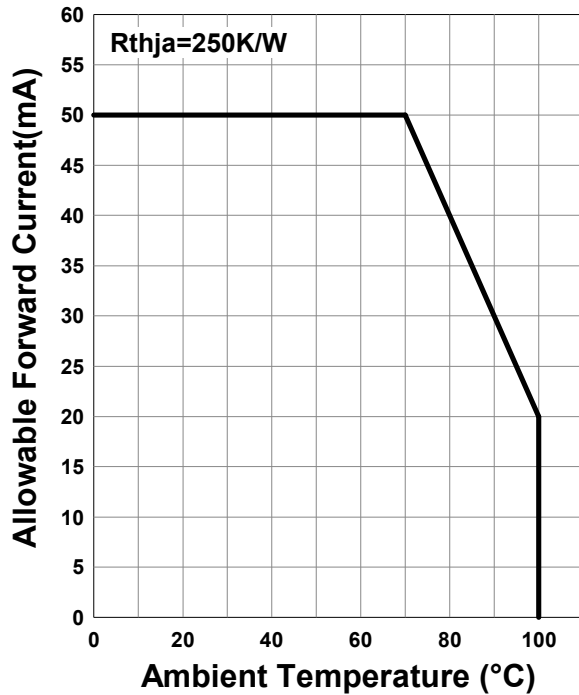
Relative Radiant Intensity - Forward Current



Forward Current - Pulse Duration

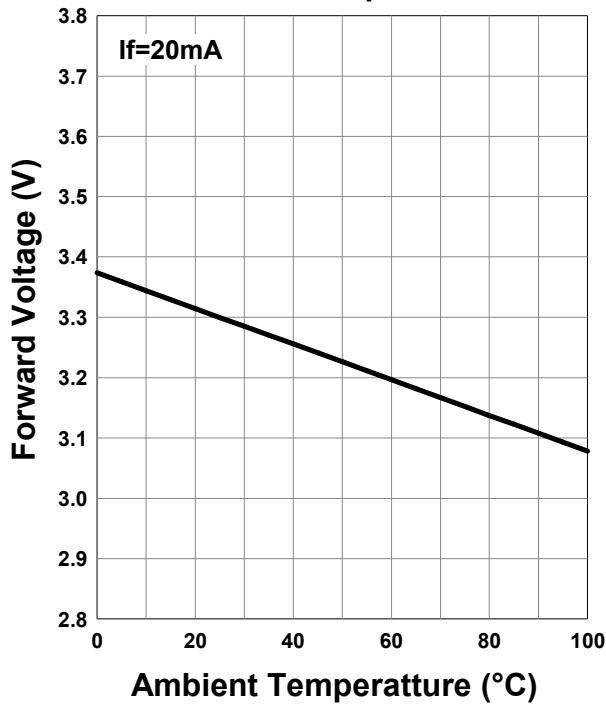


Allowable Forward Current - Ambient Temperature

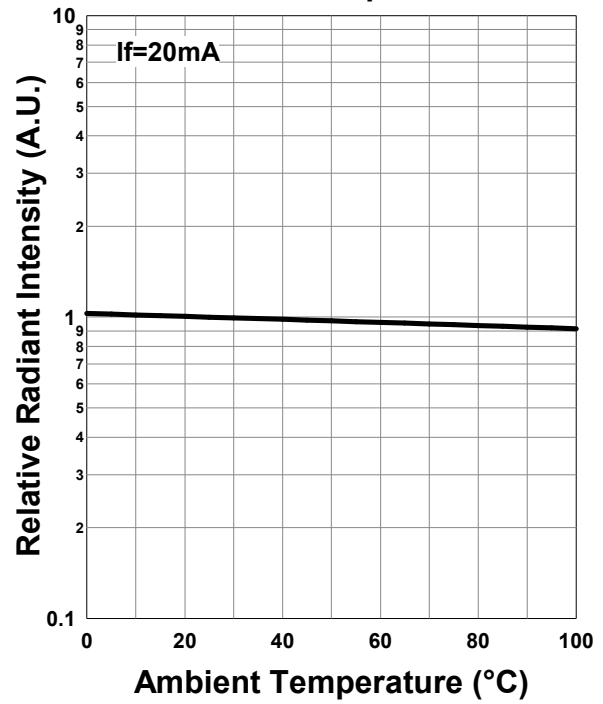


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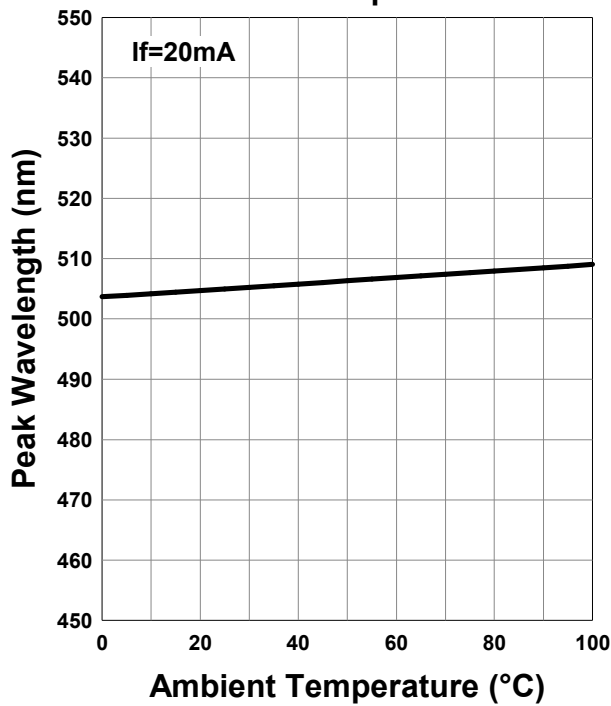
Forward Voltage - Ambient Temperature



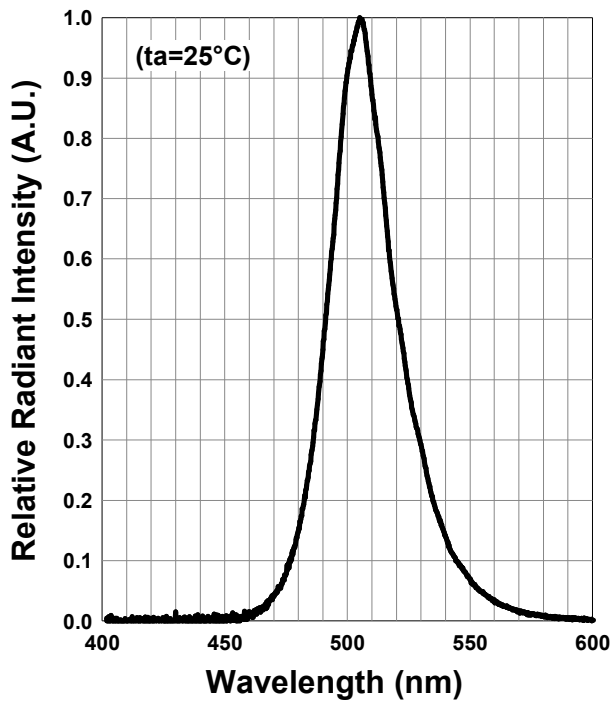
Relative Radiant Intensity - Ambient Temperature



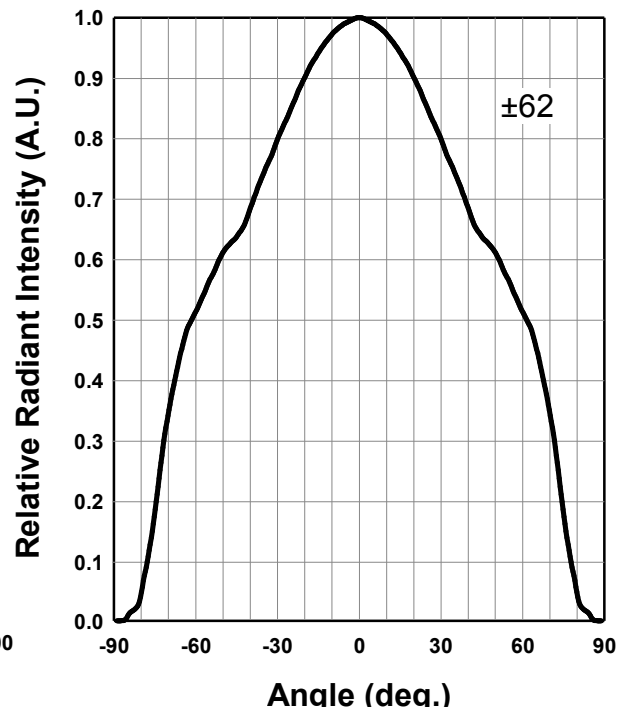
Peak Wavelength - Ambient Temperature



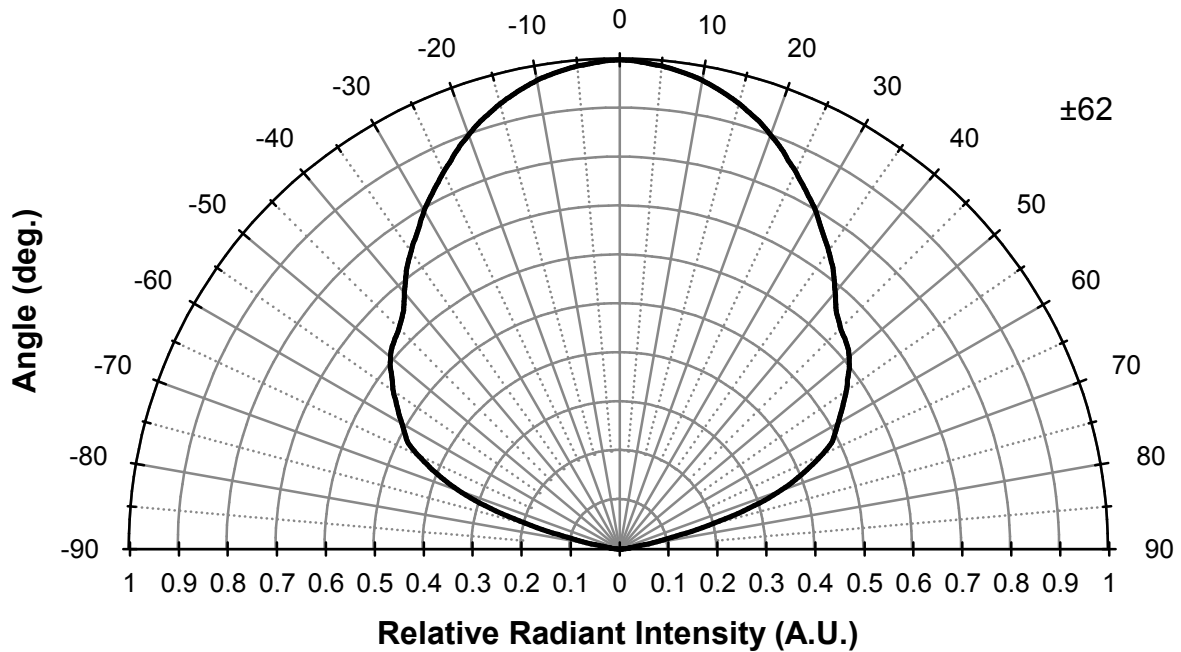
Relative Spectral Emission



Radiation Characteristics



Radiation Characteristics



Disclaimer

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Product data and parameters in this catalog are typical values based on reasonably up-to-date measurements.

Product data and parameters may vary by user application and over time.

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*Effective July 2016, Ushio Epitex Inc. is now Ushio Opto Semiconductors, Inc.